

## STU12N65M5

**Request a Quote** 

### STU12N65M5 Information





Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



### STU12N65M5 Specifications

Manufacturer Part Number	STU12N65M5
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-251-3 Short Leads, IPak, TO-251AA
Series	MDmesh? V
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	8.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	900pF @ 100V
Vgs (Max)	±25V
FET Feature	-
Power Dissipation (Max)	70W (Tc)
Rds On (Max) @ Id, Vgs	430 mOhm @ 4.3A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	I-Pak
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
	Report errors?

### STU12N65M5 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE UARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### STU12N65M5 Payment Methods



### STU12N65M5 Shipping Methods



If you have any question about STU12N65M5, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com